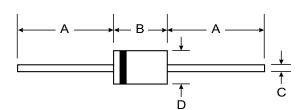


## 1.0A HIGH VOLTAGE SCHOTTKY BARRIER RECTIFIER

## **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- Surge Overload Rating to 25A Peak
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application
- High Temperature Soldering: 260°C/10 Second at Terminal
- Plastic Material: UL Flammability Classification Rating 94V-0



## **Mechanical Data**

Case: Molded Plastic

Terminals: Plated Leads -

Solderable per MIL-STD-202, Method 208

Polarity: Cathode Band

Weight: 0.3 grams (approx.)

Mounting Position: Any

Marking: Type Number

DO-41					
Dim	Min	Max			
Α	25.4	_			
В	4.1	5.2			
С	0.71	0.86			
D	2.0	2.7			
All Dimensions in mm					

## Maximum Ratings and Electrical Characteristics @ TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	SB170	SB180	SB190	SB1100	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	70	80	90	100	V
RMS Reverse Voltage		V <sub>R(RMS)</sub>	49	56	63	70	٧
Average Rectified Output Current	@ T <sub>T</sub> = 85°C	Io	1.0				Α
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		I <sub>FSM</sub>	25				А
Forward Voltage @ I <sub>F</sub> = 1.0A @ T <sub>A</sub> = 25°C		V <sub>FM</sub>	0.80				V
Peak Reverse Current @ T <sub>A</sub> = 25°C at Rated DC Blocking Voltage @ T <sub>A</sub> = 100°C		I <sub>RM</sub>	0.5 10				mA
Typical Junction Capacitance (Note 2)		Cj	80				pF
Typical Thermal Resistance Junction to Lead		R <sub>θ</sub> JL	15				K/W
Typical Thermal Resistance Junction to Ambient (Note 1)		R <sub>θ</sub> JA	50				K/W
Operating and Storage Temperature Range		T <sub>j,</sub> T <sub>STG</sub>	-65 to +125				°C

Notes:

- 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

